TED STATES PATENT AND TRADEMARK OFFICE

Application No. :

10/691,080

Confirmation No.: 9280

Applicants:

Barry E. Burke et al.

Filed:

October 22, 2003

TC/A.U.:

2818

Examiner:

C. Luu

Docket No.:

MIT8431L

For:

High-Yield, Single-Level Gate Charge-Coupled

Device Design and Fabrication

COMMISSIONER FOR PATENTS P.O. Box 1450 ALEXANDRIA, VIRGINIA 22313-1450 I hereby certify that this correspondence is being deposited on the date shown below with the United States Postal Service with sufficient postage as first class mail, under 37 CFR 1.8(a), in an envelope addressed to: Commissioner For Patents, PO Box 1450, Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT FILED PURSUANT TO THE DUTY OF DISCLOSURE UNDER 37 CFR §1.56, §1.97, AND §1.98

Pursuant to the duty of disclosure under 37 CFR §1.56, §1.97, and §1.98, the Applicants request consideration of this Information Disclosure Statement.

Compliance with 37 CFR §1.97:

This Information Disclosure Statement is hereby filed under §1.97 (c) at a time prior to the mailing date of a final action or notice of allowance.

Please apply the fee amount of \$180.00 under 1.17(p) to Deposit Account No. 19-2553. If any other fees are required, or there are any credits, please also apply such to Deposit Account No. 19-2553.

Information Cited:

The Applicants hereby make of record in the instant application the information listed on the attached two (2) pages of Forms PTO/SB/08A and PTO/SB/08B. The order of presentation of the references on the forms should not be construed as an indication of the importance of the references. A copy of each of the listed items is enclosed.

Remarks:

The Applicants respectfully request that:

- 1. The Examiner consider completely the cited information in reaching a determination concerning the patentability of the pending claims;
- 2. The enclosed two (2) pages of Forms PTO/SB/08A and PTO/SB/08B be initialed and signed by the Examiner and a signed copy returned to the undersigned Agent to evidence that the cited information has been fully considered by the Patent and Trademark Office during the examination of this application; and
- 3. The citations for the information listed on the enclosed two (2) pages of Forms PTO/SB/08A and PTO/SB/08B be printed on any patent which issues from this application.

In submitting this Information Disclosure Statement, the Applicants make no representation that a search has been performed, of the extent of any search performed, or that more relevant information does not exist. In submitting this Information Disclosure Statement, the Applicants make no representation that the information cited in the Statement is, or is considered to be, material to patentability as defined in 37 CFR §1.56(b). In submitting this Information Disclosure Statement, the Applicants make no representation that the information cited in the Statement is, or is considered to be, in fact, prior art as defined by 35 U.S.C. §102.

Notwithstanding any statements by the Applicants, the Examiner is urged to form his own conclusion regarding the relevance of the cited information. An early and favorably action is hereby requested.

Respectfully Submitted

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Sous Al

Theresa A. Lober Reg. No. 35,253

Agent for Applicants

PTO/SB/08A (07-05)

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Approved for use through 07/31/2006, OMB 0651-0031

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Complete if Known				
Application Number	10/691,080			
Filing Date	October 22, 2003			
First Named Inventor	Barry E. Burke			
Art Unit	2818			
Examiner Name	C. Luu			
Attorney Docket Number	MIT8431L			

Examiner Initials*	Cite No.1	Document Number Number-Kind Code ^{2 (# known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	A1	^{US-} 3,728,590	04-17-1973	Kim et al.	
	A2	^{US-} 3,853,634	12-10-1974	Amelio et al.	
	A3	^{US-} 5,298,448	03-29-1994	Stevens et al.	
	A4	^{US-} 4,063,992	12-20-1977	Hosack	
	A5	^{US-} 4,613,402	09-23-1986	Losee et al.	
	A6	^{US-} 5,302,544	04-12-1994	Lavine	
	A7	^{US-} 5,314,836	05-24-1994	Lavine	
	A8	^{US-} 5,556,801	09-17-1996	Hawkins et al.	
	A9	^{US-} 5,606,187	02-25-1997	Bluzer et al.	
	A10	^{US-} 5,719,075	02-17-1998	Hawkins et al.	
	A11	^{US-} 5,760,431	06-02-1998	Savoye et al.	
		US-			

FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No.1	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages	Γ.	
	Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	MM-DD-YYYY		Or Relevant Figures Appear	T⁵		
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Examiner	Date	
Signature	Considered	

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.



PTO/SB/08B (07-05) Approved for use through 07/31/2006. OMB 0651-0031

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Oubstitut				Application Number	10/691,080	
INFO	ORMATIO	N DIS	CLOSURE	Filing Date	October 22, 2003	
STA	TATEMENT BY APPLICANT			First Named Inventor	Barry E. Burke	
	//	.		Art Unit	2818	
	(Use as many sheets as necessary)			Examiner Name	C. Luu	
Sheet	2	of	2	Attorney Docket Number	MIT8431L	

Examiner	Cite	NON PATENT LITERATURE DOCUMENTS Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of	
Initials*	No.1	the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	B1	BROWNE et al., "A Nonoverlapping Gate Charge-Coupling Technology for Serial Memory and Signal Processing Applications," IEEE Jnl of Solid-State Circuits, Vol. SC11, No. 1, pp. 203-207, February 1976.	
	B2	KAPOOR, "Charge-Coupled Devices with Submicron Gaps," IEEE Electron Device Ltrs., Vol. EDL-2, No. 4, pp. 92-94, April 1981.	
	В3	SLOTBOOM et al., "Submicron CCD memory structures fabricated by electron-beam lithography," Proc. IEDM '84, paper 11.6, pp. 308-311, 1984.	
	B4	GAJAR et al., "An ionic liquid-channel field-effect transistor," J. Electrochem. Soc., V. 139, No. 10, pp. 2833-2840, October 1992.	
	B5	YAMADA et al., "Driving Voltage Reduction in a Two-Phase CCD by Suppression of Potential Pockets in Inter-Electrode Gaps," IEEE Trans. on Electron Devices, V. 44, No. 10, pp. 1580-1587, October 1997.	
	B6	OKADA et al., "Performance of FT-CCD image sensor with Single Layer Poly-Silicon Electrode," 1999 IEEE Workshop on Charge-Coupled Devices and Advanced Imager Sensors, pp. 219-222, Nagano, Japan, June 1999.	
	В7	BURKE et al., "Charge-coupled device made with a single polysilicon level," Massachusetts Institute of Technology Lincoln Laboratory Solid State Research Quarterly Technical Report, pp. 31-37, March 1, 2002.	

Examiner	Date .	 -
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached. This collection of information is required by 37 CFR 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO:

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